IN THE CLAIMS:

1.-22. (Canceled)

23. (Currently Amended) A liquid crystal display device comprising:

a twisted nematic (TN) liquid crystal panel portion comprising thin film transistors; and

a backlight portion for supplying light from a rear surface side of the TN liquid crystal panel portion, wherein:

the thin film transistors of the TN liquid crystal panel portion each have a polycrystalline silicon semiconductor layer comprising a channel region, a source region, and a drain region, the source region and the drain region respectively located on opposite sides of the channel region, the drain region comprising a lightly doped drain (LDD) region;

the relationship of expression (2)

$$(R+30)\cdot W < 1\times 10^3 \qquad (2)$$

is satisfied, where R (kΩ/□) is the sheet resistance of the LDD region and W (μm) is the channel width of the channel region, the sheet resistance of the LDD region being from about 20 kΩ/□ to about 100 kΩ/□, and

the highest luminance of the backlight portion is not greater than 5000 cd/m^2 so that the photoelectric current range of the display device is thereby regulated to suppress OFF current in the thin film transistors during irradiation of the display device with light.

24. (Previously Presented) The liquid crystal display device according to claim 23, wherein the channel width W of the channel region is not greater than 2 μm.

25. (Previously Added) The liquid crystal display device according to claim 23, wherein the sheet resistance of the LDD region is in the range of from 20 kΩ/□ to 100 kΩ/□.

26. (Previously Added) The liquid crystal display device according to claim 24, wherein the sheet resistance of the LDD region is in the range of from 20 kΩ/□ to 100 kΩ/□.